

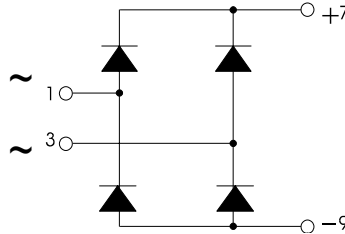
Single Phase Rectifier Bridges

PSB 95

$I_{dAVM} = 95 \text{ A}$
 $V_{RRM} = 800-1800 \text{ V}$

Preliminary Data Sheet

V_{RSM} V	V_{RRM} V	Type
800	800	PSB 95/08
1200	1200	PSB 95/12
1400	1400	PSB 95/14
1600	1600	PSB 95/16
1800	1800	PSB 95/18



Symbol	Test Conditions	Maximum Ratings
I_{dAVM}	$T_C = 85^\circ\text{C}$, module	95 A
I_{FSM}	$T_{VJ} = 45^\circ\text{C}$ $V_R = 0$ $t = 10 \text{ ms}$ (50 Hz), sine	1200 A
	$t = 8.3 \text{ ms}$ (60 Hz), sine	1350 A
	$T_{VJ} = T_{VJM}$ $V_R = 0$ $t = 10 \text{ ms}$ (50 Hz), sine	1040 A
	$t = 8.3 \text{ ms}$ (60 Hz), sine	1120 A
$\int i^2 dt$	$T_{VJ} = 45^\circ\text{C}$ $V_R = 0$ $t = 10 \text{ ms}$ (50 Hz), sine	7200 $\text{A}^2 \text{ s}$
	$t = 8.3 \text{ ms}$ (60 Hz), sine	9110 $\text{A}^2 \text{ s}$
	$T_{VJ} = T_{VJM}$ $V_R = 0$ $t = 10 \text{ ms}$ (50 Hz), sine	5400 $\text{A}^2 \text{ s}$
	$t = 8.3 \text{ ms}$ (60 Hz), sine	6270 $\text{A}^2 \text{ s}$
T_{VJ}		-40 ... + 150 $^\circ\text{C}$
T_{VJM}		150 $^\circ\text{C}$
T_{stg}		-40 ... + 125 $^\circ\text{C}$
V_{ISOL}	50/60 HZ, RMS $t = 1 \text{ min}$	2500 V ~
	$I_{ISOL} \leq 1 \text{ mA}$ $t = 1 \text{ s}$	3000 V ~
M_d	Mounting torque (M5)	5 Nm
	Terminal connection torque (M5)	5 Nm
Weight	typ.	220 g

Features

- Package with screw terminals
- Isolation voltage 3000 V~
- Planar glasspassivated chips
- Blocking voltage up to 1800 V
- Low forward voltage drop
- UL registered, E 148688

Applications

- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

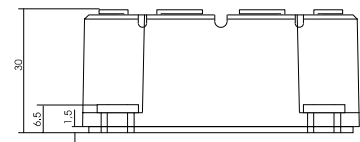
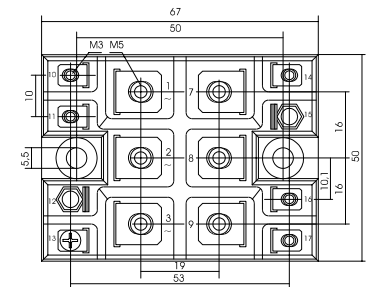
Advantages

- Easy to mount with two screws
- Space and weight savings
- Improved temperature and power cycling capability

Package, style and outline

Dimensions in mm (1mm = 0.0394")

Symbol	Test Conditions	Characteristic Value
I_R	$V_R = V_{RRM}$ $T_{VJ} = 25^\circ\text{C}$	$\leq 0.3 \text{ mA}$
	$V_R = V_{RRM}$ $T_{VJ} = T_{VJM}$	$\leq 6.0 \text{ mA}$
V_F	$I_F = 150 \text{ A}$ $T_{VJ} = 25^\circ\text{C}$	$\leq 1.5 \text{ V}$
V_{TO}	For power-loss calculations only	0.8 V
r_T	$T_{VJ} = T_{VJM}$	5.0 $\text{m}\Omega$
R_{thJC}	per diode; DC current	0.9 K/W
	per module	0.225 K/W
R_{thJK}	per diode; DC current	1.1 K/W
	per module	0.275 K/W
d_s	Creeping distance on surface	8.0 mm
d_A	Creeping distance in air	4.5 mm
a	Max. allowable acceleration	50 m/s^2



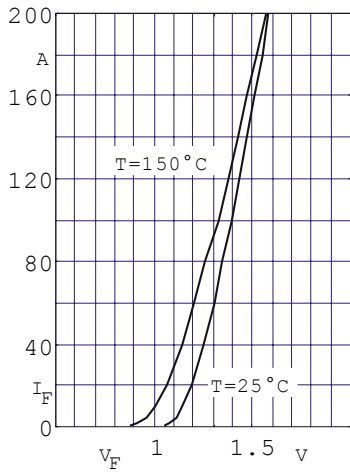


Fig. 1 Forward current versus voltage drop per diode

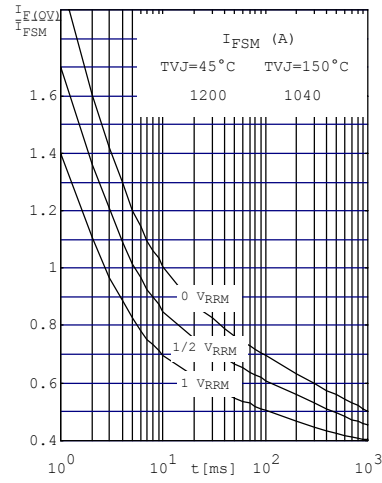


Fig. 2 Surge overload current per diode I_{FSM} : Crest value. t: duration

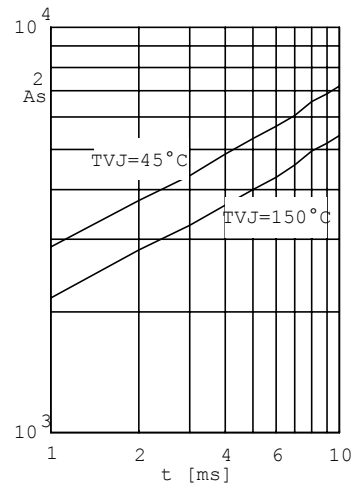


Fig. 3 $\int i^2 dt$ versus time (1-10ms) per diode (or thyristor)

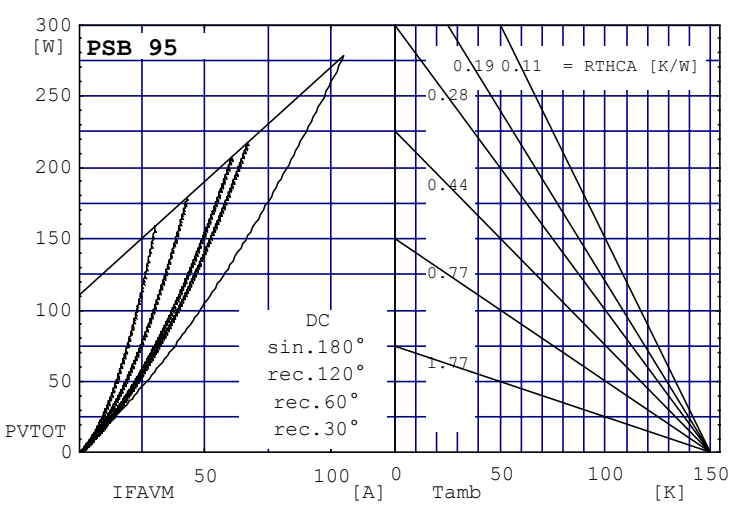


Fig. 4 Power dissipation versus direct output current and ambient temperature

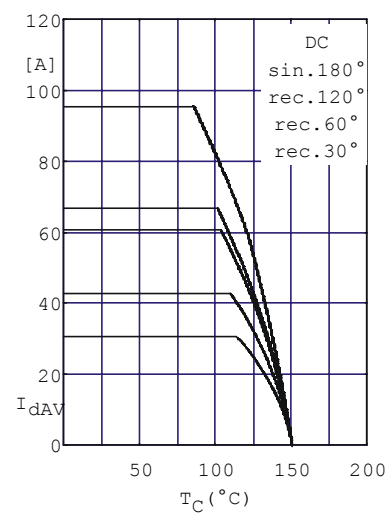


Fig.5 Maximum forward current at case temperature

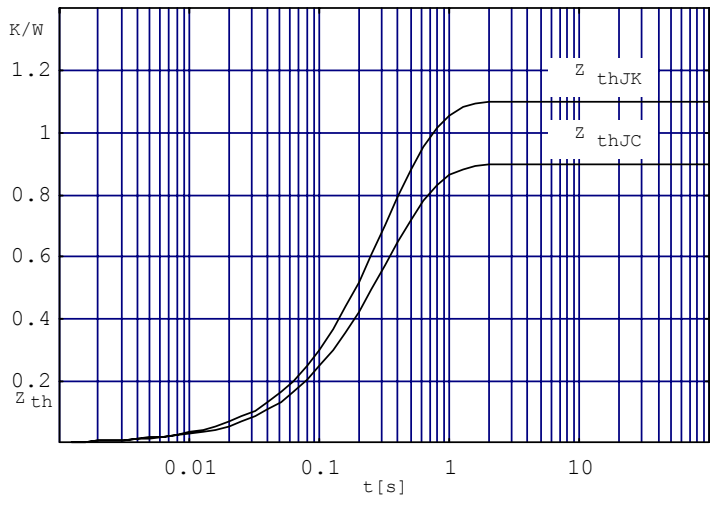


Fig. 6 Transient thermal impedance per diode (or thyristor), calculated